


Form 1449* <b>INFORMATION DISCLOSURE STATEMENT IN AN APPLICATION</b>	Docket Number: G&C 122.46-US-U1	Application Number: 10/724,942
	Applicants: Christopher W. Coldren et al.	
	Filing Date: December 1, 2003	Group Art Unit: 2874

U.S. PATENT DOCUMENTS						
EXAMINER INITIAL	DOCUMENT NO.	DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE
FOREIGN PATENTS						
	DOCUMENT NO.	DATE	COUNTRY	CLASS	SUBCLASS	TRANSLATION
						YES NO
NON-PATENT DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.)						
			Akage, Y., et al., "Wide bandwidth of over 50 GHz travelling-wave electrode electroabsorption modulator integrated DFB lasers," Electronics Letters, 37(5):299-300, March 2001			
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			Barton, J.S., et al., "Integration of a Mach-Zehnder Modulator with Sampled Grating Distributed Bragg Reflector Laser," Proc. Integrated Photonics Research Conference, paper no. 1FC3-1, July 17-19, 2002			
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			Walker, R.G., "High-speed III-V semiconductor Intensity Modulators," IEEE J. Quantum Electronics, 27(3):654-667, March 1991			

EXAMINER: 	DATE CONSIDERED: 6/20/05
EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; draw line through citation if not in conformance and not considered. Include copy of this form for next communication to the Applicant.	

